Non-fullerene acceptor (NFA) materials have posed new paradigms for the design of organic solar cells (OSC), whereby efficient carrier generation is obtained with small driving forces, in order to maximize the open-circuit voltage ($V_{OC}$). In this paper we present a coarse grained mixed quantum-classical model that provides insights into the charge generation process for small energy offset interfaces. We have studied the influence of the energetic driving force and the vibronic effects on the charge generation and photovoltaic energy conversion. By analyzing the effects of the Holstein and Peierls vibrational couplings, we find, quite generally, that vibrational couplings produce an overall effect of improving the charge generation. However, the two vibronic mechanisms play different roles: the Holstein relaxation mechanism decreases the charge generation whereas the Peierls mechanism always assists the charge generation. By examining the electron-hole binding energy as a function of time, we evince two distinct regimes for charge dissociation: the temperature independent excitonic spread on the sub-100 fs timescale whereas the dissociation of the charge-transfer state occurs on the timescale of tens to hundreds of picoseconds, depending on the temperature, so that when the electron-hole pair reaches the interface its binding energy is much smaller that the initial excitonic binding energy.
I. INTRODUCTION

The photovoltaic conversion process in organic solar cells (OSC) consists of several steps that directly affect the power conversion efficiency (PCE) of the device. Charge photogeneration has always been a major concern in regard to cell efficiency, so that energy cascades were considered essential for overcoming the Coulomb attraction and generating free carriers as quickly as possible in order to prevent losses from recombination. Consistent progress was achieved by optimizing the transport properties of the active materials and the interface morphology between them. The first efficient solar cells were fabricated with fullerene derivatives as acceptor materials, which provide remarkable electron-accepting and electron-transport capabilities, low reorganization energy and good miscibility. However, improvements in cell efficiency with fullerene-based OSC stagnated around 12%. Then, circa 2017, non-fullerene based solar cells caught up with a prototype that presented 13% of PCE. Thereafter the photovoltaic efficiency of non-fullerene OSC have increased strongly, nearing the 20% efficiency mark. The photoconversion efficiencies of fullerene-based OSC have saturated due to excessive energy losses at the donor-acceptor (D-A) interface. Since the exciton binding energy is stronger in organic molecules than in inorganic crystalline materials, the internal electric field of the D-A interface was considered essential for generating the charge separated state. Moreover, guidelines based on fullerene-based OSCs indicated that the photocurrent should fall abruptly for small charge separation driving forces. That notion was supported by the analogous charge separation process in natural photosynthesis, in which case a strong energetic driving force is required to guarantee free charge generation. Natural photosynthesis, however, has not evolved for producing energy at high efficiencies.

The use of non-fullerene acceptors (NFAs) made it possible to build organic solar cells with photovoltaic efficiencies comparable to the inorganic counterparts. The improvements have been achieved empirically, though, by decreasing the energetic driving force of the D-A interface while keeping the quantum efficiency high. A deeper understanding of the molecular processes responsible for the photogeneration is desirable for providing guidance on the rational design of better devices. The long standing question of how the exciton gives rise to free separated charges has been examined in the past for polymer/fullerene blends, both experimentally and theoretically, but not as much for the new acceptor materials. It is also crucial to determine the relevance of entropic versus enthalpic effects for the power conversion as the driving force continues to decrease. Herein, we aim to shed some light on these issues.
Experimental evidence has shown the relevance of vibronic effects during the charge separation and charge transport processes, thereby suggesting that the coupling between electrons and phonons plays an important role in dissociating the electron-hole pair across the interface.[19][24] In fact, molecular vibrations can accelerate electron transfer reactions,[25][26] so that the coupling between electronic and vibrational degrees of freedom can be as important as the electronic and morphological features. The understanding of such mechanisms in organic materials can open new paths in the development of material blends with better performance.[22]

In this work we address these problems by means of theoretical simulations of the charge generation dynamics and photovoltaic efficiency in a model D-A interface, taking into account quantum mechanical and dissipative effects. The process is modelled on the basis of the system-bath partition approach. The degrees of freedom directly associated with the process of photoinduced charge generation, namely the electron and hole quantum states and their vibrational reorganization modes, are described by a mixed quantum-classical hamiltonian evaluated within the framework of the Ehrenfest method. The system-bath coupling is described within the framework of the Redfield theory. We have studied the influence of the energetic driving force and vibronic effects on the charge generation and photovoltaic energy conversion. By analyzing the effects of the Holstein and Peierls vibrational couplings, we find, quite generally, that vibrational couplings produce an overall effect of improving the charge generation. However, the two vibronic mechanisms play different roles: the Holstein relaxation mechanism decreases the charge generation whereas the Peierls mechanism always assists the charge generation. Last we examine the electron-hole binding energy as a function of time and evince two distinct regimes for charge dissociation: the temperature independent excitonic spread on the sub-100 fs timescale and the charge-transfer state dissociation on the timescale of tens of picoseconds, so that when the electron-hole pair reaches the interface its binding energy is much smaller that the initial excitonic binding energy.

II. THEORY AND METHODS

By adopting the system-bath approach we partition the hamiltonian of the charge generation process as

$$H = H_S + H_B + H_{SB},$$

where the system hamiltonian, $H_S$, comprises the degrees of freedom directly associated with the process of photoinduced charge generation, namely the electron and hole quantum states and their
vibrational reorganization modes, herein described as classical degrees of freedom. Therefore, $H_S$ is actually a mixed quantum-classical hamiltonian treated within the framework of the Ehrenfest method. The environment hamiltonian, $H_B$, accounts for all the remaining degrees of freedom of the D-A interface and its environment, namely the vibrational degrees of freedom and the fluctuations of the dielectric background, which we describe as an ensemble of quantum harmonic oscillators. Finally, $H_{SB}$ accounts for the interactions between the electron-hole pair and the environment. The system-bath coupling is described within the framework of the Redfield theory. Next we describe the model system for the D-A interface and, then, the implementation of the Redfield equations.

A. Donor-Acceptor System

As shown in Figure 1-a), the D-A interface is modelled as a two-dimensional (2D) lattice, with energy profile corresponding to a staggered (type II) interface. Upon photoexcitation of a molecular site the electron-hole pair diffuses to the interface, where it gives rise to a charge transfer (CT) state. Herein, we assume the photoexcitation of a molecular site in the donor material, however, since the model has particle-hole symmetry, the forthcoming results are equally valid for an exciton created in the acceptor material. If the CT state overcomes the electron-hole binding and dissociates before recombination – either radiative or non-radiative – annihilates the CT state, a pair of free charge carriers with energy $E_{CS} = E_{CB}(A) - E_{VB}(D)$ is produced, with $E_{CS}$ designating the energy of the charge separated state. The energy difference $E_{opt} - E_{CS}$ can be associated with the energetic driving force of the charge generation process. In the present model, the electron and hole populations are eventually collected at the respective drain layers, here positioned 0.3 eV below $E_{CB}(A)$ and 0.3 eV above $E_{VB}(D)$, in analogy to the cathode and anode terminals. The spatial arrangement of the 2D D-A interface model is shown in Figure 1-b), where each site of the lattice represents a molecular site. Periodic boundary conditions are applied along the $y$ direction.

The paraboloids depicted in Figure 1-a) describe the local confinement potential felt by the electron and the hole at a given molecular site. We assume that the parabolic confinement potential undergoes a vibrational reorganization whenever charge is transferred in or out of the molecular site (see Figure 2). This mechanism gives rise to coherent vibronic effects that we describe within the framework of the Ehrenfest method. The density profile of the electron and hole in the
FIG. 1. Model representation of the donor-acceptor interface. Panel a) depicts the energetics of the D-A interface. The outermost layers are the electron and hole drains. The vertical arrow indicates the photoexcitation of the electron-hole pair. The paraboloid describes the confining potential energy surface of the molecular site. Panel b) depicts the spatial configuration of the D-A interface. Each molecule is described as a site in a 2D lattice. Electron and hole can coexist on the same site, or occupy separate sites.

A molecular site is given by the gaussian

$$g(\vec{r} - \vec{R}) = \sqrt{\frac{2}{\pi \ell^2}} \exp \left[ - \left( \frac{\vec{r} - \vec{R}}{\ell} \right)^2 \right],$$

with $\vec{R}$ designating the position of the molecular site, and $\ell$ is the confinement radius of the molecular site, given by

$$\ell = \sqrt{2\hbar^2/(m_\varepsilon \varepsilon)}$$

for a gaussian wavepacket of on-site energy $\varepsilon$.

To write the system Hamiltonian, $H_S$, we assume an orthogonal basis set comprised of diabatic electronic states $\{|i\rangle\}$ associated with the molecular sites:

$$H_S \equiv H_{\text{el/hl}} = \sum_i^N \left\{ E_i^{\text{el/hl}} + \varepsilon_i(t) - \Phi_i^{\text{el/hl}}(t) \right\} |i\rangle \langle i| + \sum_{i \neq j}^N V_{ij}(t) |i\rangle \langle j|,$$
with \( N \) denoting the total number of molecular sites in the lattice. Hereafter, we use the symbols \{ \ket{i}, \ket{j} \} to designate exclusively the local diabatic quantum states. The on-site terms of \( H_S \) are defined as \( E_i^{\text{el}} = E_i^{CB}, E_i^{\text{hl}} = E_i^{VB}, \) \( \varepsilon_i \) is the confinement energy associated with site \( i \), as given by Eq. (3), and \( \xi_i^{\text{el/hl}} \) represents the electron-hole electrostatic interaction, given by the mean-field potential

\[
\Phi_i^{\text{el/hl}}(t) = \xi_{\text{bind}} \left( \sum_j \frac{P_j^{\text{el/hl}}}{1 + d_{ij}} \right).
\] (5)

In Eq. (5), \( \xi_{\text{bind}} \) is assumed to be the same for the electron and hole excitations. \( P_j^{\text{el}} (P_j^{\text{hl}}) \) designates the average electronic (hole) population on site \( j \) and \( d_{ij} = |\vec{R}_i - \vec{R}_j| \) is the distance between sites \( i \) and \( j \). Thus, the total electron-hole binding energy is given by \( E_{\text{bind}} = \text{Tr}[\sigma^{\text{el}}\Phi^{\text{el}} + \sigma^{\text{hl}}\Phi^{\text{hl}}] \), with \( \sigma \) representing the reduced density matrix.

The coupling \( V_{ij} \) between lattice sites is given by

\[
V_{ij} = V_0 F(\ell_i, \ell_j, d_{ij}) = V_0 \left[ \frac{2\ell_i \ell_j}{\ell_i^2 + \ell_j^2} \exp \left( \frac{-d_{ij}^2}{\ell_i^2 + \ell_j^2} \right) \right],
\] (6)

where \( V_0 \) is the bare electronic coupling and the form factor \( F \) results from the overlap between gaussian wavepackets located at lattice sites \( i \) and \( j \)

\[
F(\ell_i, \ell_j, d_{ij}) = \int g_i(\vec{r} - \vec{R}_i) \ g_j(\vec{r} - \vec{R}_j) dxdy.
\] (7)

The time dependence of \( \varepsilon_i(t) \) and \( V_{ij}(t) \), which comprise Eq. (4), gives rise to intra-molecular and inter-molecular vibronic couplings that we associate with the Holstein and Peierls couplings, respectively.

We describe the coherent coupling between the electron-hole states and the intra-molecular vibrational degree of freedom via the Ehrenfest method. The vibrational hamiltonian coupled to the electron-hole in the site \( i \) is given by

\[
h_i = \frac{p_i^2}{2\mu} + \frac{\mu \Omega^2}{2}(\ell_i - \ell_o)^2 + W^{\text{eh}} + Q^{\text{thermo}},
\] (8)

where \( \ell_i \) is the vibrational coordinate associated with the molecular site \( i \) and \( p_i \) is the conjugate momentum. In addition, \( \ell_o \) is the confinement length for an empty site, \( \mu \) is the effective mass of the vibrational mode and \( \Omega \) is the frequency of the relevant normal mode. The energy \( W^{\text{eh}} \) is the work exchanged with the electronic degrees of freedom via the Ehrenfest force \( F^{\text{eh}} \) and \( Q^{\text{thermo}} \) is the heat exchanged with the classical thermostat. A similar hamiltonian has been considered by
FIG. 2. Schematics of the electronic relaxation. The parabola describes the confinement potential felt by
the electron (or hole) with its gaussian wavefunction profile. On the left-hand side we show an empty
molecular site, with confinement energy $\varepsilon_o$ and the corresponding confinement length $\ell_o$. On the right-hand
side we show an occupied molecular site, with on-site energy $\varepsilon$ and $\ell$. The electronic relaxation energy is
$\Delta \varepsilon = \varepsilon_o - \varepsilon$.

Egorova et al.\textsuperscript{29,30} for quantum intra-molecular degrees of freedom. The Ehrenfest force that acts
on the vibrational coordinate of a given molecular site $k$ is

$$F_k^{eh} = F_k^{el} + F_k^{hl} = -\frac{\partial U^{el}}{\partial \ell_k} - \frac{\partial U^{hl}}{\partial \ell_k},$$

with $U^{el} = Tr[\sigma^{el}H^{el}]$ and $U^{hl} = Tr[\sigma^{hl}H^{hl}]$. Solving equation (9) we obtain (see Appendix A)

$$F_k^{eh} = - (\sigma_{kk}^{el} + \sigma_{kk}^{hl}) \frac{d\varepsilon_k}{d\ell_k} - \sum_{i \neq j} (\sigma_{ij}^{el} + \sigma_{ij}^{hl}) \frac{\partial V_{ij}}{\partial \ell_k}. \tag{10}$$

The first term on the right-hand side (RHS) of Equation (10) is responsible for the relaxation of the
molecular site due to its charge occupation; this is the classical work exchanged between electronic
and vibrational degrees of freedom. The second term gives rise to coherent vibronic effects, for it is
proportional to the off-diagonal elements of $\sigma$ and couples the electronic and nuclear coordinates
via $\partial V_{ij}/\partial \ell_k$.\textsuperscript{31}

The classical equations of motion derived from Eq. (8) are solved with the velocity Verlet
algorithm, coupled to a classical bath, described by the Berendsen thermostat\textsuperscript{32} with relaxation
constant $\gamma^{-1} = 0.1$ ps. The perturbing forces change the equilibrium configuration of the parabolic
confining potential, which reacts with a restoring force $F^{res} = -\mu \Omega^2 (\ell - \ell_o)$.

B. Redfield Coupling with the Environment

A rigorous method to derive the equations of motion for the system hamiltonian $H_S$ coupled
with the environment is based on the application of projection operators $\mathcal{P}$ and $\mathcal{Q}$, where $\mathcal{Q} \equiv 1 -$
The projection operator \( P \) is defined as
\[
P \rho = \frac{\text{tr}_B(\rho) \otimes \rho_B}{\text{tr}_B\{e^{-H_B/kT}\}},
\]
which is assumed to be in thermal equilibrium, that is \( \text{tr}_B\{H_{SB}\rho_B\} = 0 \), and
\[
H_B = \sum_{\alpha} \hbar \omega_{\alpha}(b_{\alpha}^\dagger b_{\alpha} + \frac{1}{2}).
\]

Although the Nakajima-Zwanzing equations provide an exact framework for the dynamics of \( H_S \), they are not computationally practical. Thus, approximation steps are required to obtain the stationary Redfield equations used in this work. These approximation steps consist of: (i) first, the system-bath coupling is treated perturbatively using the second order Born approximation; (ii) since the resulting equation is not local in time, the local approximation \( \sigma(t')\rho_B \approx \sigma(t)\rho_B \) is invoked; and (iii) the formalism assumes that the dynamics of the system does not alter the bath significantly, which is considered to be in equilibrium. Then, the upper limit of the time integration is replaced by infinity, and a local-time equation of motion for the reduced density matrix. All the above approximation steps are incorporated in Eq. (13)

\[
\frac{\partial \sigma(t)}{\partial t} = -\frac{1}{\hbar^2} \int_0^\infty dt' \text{tr}_B\{[H_{SB}(t),[H_{SB}(t'),\sigma(t)\rho_B]]\},
\]

where we have written \( H_{SB}(t) = e^{\frac{i}{\hbar}(H_S+H_B)t}H_{SB}e^{-\frac{i}{\hbar}(H_S+H_B)t} \) in the interaction picture. Using the adiabatic representation for the system hamiltonian, \( H_S\ket{\varphi_a} = E_a\ket{\varphi_a} \), the Redfield equation for the reduced density matrix \( \sigma \) reads

\[
\frac{\partial \sigma_{ab}(t)}{\partial t} = -i\omega_{ab}\sigma_{ab} + \sum_{c,d} R_{abcd}\sigma_{cd}(t)
\]

where \( \omega_{ab} = (E_a - E_b)/\hbar \) designates the eigenfrequencies and \( R_{abcd} \) is the Redfield relaxation tensor. The first term on the RHS accounts for the coherent quantum dynamics of \( S \) whereas the second term describes the interaction of \( S \) with the environment. The Redfield tensor can be written in terms of correlation functions of the system-bath coupling

\[
R_{abcd} = \Gamma^+_{dbac} + \Gamma^-_{dbac} - \sum_n \Gamma^+_{anmc}\delta_{db} - \sum_n \Gamma^-_{dnmb}\delta_{ac}
\]
where

\[ \Gamma_{abcd}^+ = \frac{1}{\hbar^2} \int_0^\infty d\tau e^{-i\omega_{cd}\tau} \langle \langle a | \hat{H}_{SB}(\tau) | b \rangle \langle c | H_{SB} | d \rangle \rangle_B, \]  

(16)

\[ \Gamma_{abcd}^- = \frac{1}{\hbar^2} \int_0^\infty d\tau e^{-i\omega_{ab}\tau} \langle \langle a | H_{SB} | b \rangle \langle c | \hat{H}_{SB}(\tau) | d \rangle \rangle_B, \]  

(17)

with \( \hat{H}_{SB}(t) = e^{(i/\hbar)H_{B}t} H_{SB} e^{-(i/\hbar)H_{B}t} \) and \( \langle \cdots \rangle_B \) designates the thermal average over the bath degrees of freedom.

The coupling of electrons and holes with the quantum bath is described by the Holstein model, which has been used, together with the Peierls model, to describe polaronic effects in molecular crystals. For the intra-molecular electron-phonon relaxation, we have

\[ H_{SB} = \sum_{\alpha} \sum_i g_{i,\alpha} \hbar \omega_{\alpha} |i\rangle \langle i| (b_{\alpha}^+ + b_{\alpha}) \]  

(18)

which contains the dimensionless parameter \( g_{i,\alpha} \) for electron-phonon coupling that is associated with the molecular site \( i \) and the \( \alpha \)th bath mode. The strength of the system-bath coupling is given by \( C_{i,\alpha} \equiv g_{i,\alpha} \hbar \omega_{\alpha} \). Thus, from Eqs. (16) and (17) we can derive the Redfield relaxation tensors

\[ \Gamma_{abcd}^+ = \sum_{i,j} \frac{\Lambda_{ab}^i \Lambda_{cd}^j}{\pi \hbar} \int_0^\infty d\omega J_{ij}(\omega) \int_0^\infty d\tau \left[ (n(\omega) + 1) e^{-i(\omega + \omega_{ab})\tau} + n(\omega) e^{i(\omega - \omega_{ab})\tau} \right], \]  

(19)

\[ \Gamma_{abcd}^- = \sum_{i,j} \frac{\Lambda_{ab}^i \Lambda_{cd}^j}{\pi \hbar} \int_0^\infty d\omega J_{ij}(\omega) \int_0^\infty d\tau \left[ (n(\omega) + 1) e^{i(\omega - \omega_{ab})\tau} + n(\omega) e^{-i(\omega + \omega_{ab})\tau} \right]. \]  

(20)

The expression for the \( \Gamma \) rates, above, make use of the system-bath interaction spectral density (SD) \( J_{ij}(\omega) = \pi \sum_{\alpha} C_{i,\alpha} C_{j,\alpha} \delta(\omega - \omega_{\alpha}) \) (to be defined ahead) and the Planck thermal distribution \( n(\omega) = \frac{1}{e^{\hbar \omega / kT} - 1} \), calculated with the instantaneous subsystem S temperature \( T \) and frequency \( \omega \). We also define \( \sum_{i} \Lambda_{ab}^i \equiv \sum_{i} \langle \phi_a | i \rangle \langle i | \phi_b \rangle \), recalling that \( \{ |i\rangle, |j\rangle \} \) designate the diabatic on-site quantum states whereas the \( \{ |\phi\rangle \} \) states comprise the adiabatic basis set.

To calculate Eqs. (19) and (20), we assume that the interaction spectral density is described by Drude-Lorentz distribution, \( J(\omega) = 2\lambda \frac{\omega_{\alpha}}{\omega^2 + \omega_{\alpha}^2} \), and also that the phonon modes of different sites are uncorrelated \( J_{ij}(\omega) = J(\omega) \delta_{ij} \). The Drude cutoff frequency was set to \( \omega_c^{-1} = 25 \) fs, due to the coupling of the electronic degrees of freedom with the high energy phonon modes associated to the stretch normal mode of the C=C bond. It determines the peak of the spectral density; when the relevant frequencies of the system are much lower than then \( \omega_c \) the reservoir behaves like an Ohmic heat bath. Considering these definitions, the reorganization energy can be related...
to $J(\omega)$ as

$$\lambda = \frac{1}{\pi} \int_0^{\infty} d\omega \frac{J(\omega)}{\omega}. \quad (21)$$

Using the one sided delta function definition $\int_0^{\infty} d\tau e^{\pm i(\omega + \Omega)\tau} = \pi \delta(\omega + \Omega) \pm i \mathcal{P} \frac{1}{\omega + \Omega}$, where $\mathcal{P}$ denotes the principal Cauchy value, the real part of Redfield tensor elements are given by

$$\text{Re}\left[\Gamma_{abcd}^+\right] = \frac{1}{\hbar} \sum_i \Lambda_{ab}^i \Lambda_{cd}^i \begin{cases} J(\omega_{cd})n(\omega_{cd}) & \text{if } \omega_{cd} > 0 \\ J(\omega_{dc})[n(\omega_{dc}) + 1] & \text{if } \omega_{dc} > 0 \\ \lim_{\omega \to 0} J(\omega)n(\omega) & \text{if } \omega_{cd} = 0 \end{cases} \quad (22)$$

$$\text{Re}\left[\Gamma_{abcd}^-\right] = \frac{1}{\hbar} \sum_i \Lambda_{ab}^i \Lambda_{cd}^i \begin{cases} J(\omega_{ab})[n(\omega_{ab}) + 1] & \text{if } \omega_{ab} > 0 \\ J(\omega_{ba})n(\omega_{ba}) & \text{if } \omega_{ba} > 0 \\ \lim_{\omega \to 0} J(\omega)n(\omega) & \text{if } \omega_{ab} = 0 \end{cases} \quad (23)$$

For the Drude-Lorentz SD, we have $\lim_{\omega \to 0} J(\omega)n(\omega) = 2\lambda \frac{k_B T}{\hbar \omega_c}$. The real part determines the relaxation of the system. The imaginary part can be expressed in terms of principal value integrals and introduce terms that modify the transition frequencies. Such energy shifts are small and generally bring no qualitative contribution to the dynamics of $\sigma$, therefore, the imaginary part is disregarded.

### III. RESULTS AND DISCUSSION

#### A. System Preparation

The parameters used in the simulations are presented in Table I. Using these parameters, the set of coupled differential equations produced by Eq. (14) are solved numerically by a fourth order adaptive step size Runge-Kutta method.

We consider a Frenkel exciton that has been photoexcited in the center of the donor region, as shown in Figure 3. The figure uses the confinement length $\ell_i$ as the radius of the molecular sites. We consider a square lattice with lattice parameter $a = 1.3$ nm. The effective electronic coupling between nearest neighbors (nn) is set to be $V_{nn} = -40$ meV, as given by Eq. (6), which is in agreement with other molecular crystal models.\cite{22,40,42,48,49} Likewise, the electronic coupling between next-nn sites is $V_{nnn} = -1.4$ meV, owing to the bigger distance. We also recall that the inter-molecular electronic couplings $V_{ij}$ are time-modulated by the form factor $F(\ell_i, \ell_j, d_{ij})$, due
TABLE I. Values and description of the parameters used in calculations

<table>
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<th>value</th>
<th>description</th>
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</thead>
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<tr>
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<td>( N )</td>
<td>84</td>
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<td>( \ell_0 )</td>
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<td>confinement length for the empty site</td>
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<td>( V_0 )</td>
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<td>bare electronic coupling</td>
</tr>
<tr>
<td>( d_{ij} )</td>
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<td>distance of nearest neighbor sites</td>
</tr>
<tr>
<td>( \xi_{\text{bind}} )</td>
<td>0.2 eV</td>
<td>electron-hole coupling constant</td>
</tr>
<tr>
<td>( H_{SB} )</td>
<td>( \lambda )</td>
<td>50 meV reorganization energy</td>
</tr>
<tr>
<td>( \omega_\chi )</td>
<td>1334 cm(^{-1})</td>
<td>cutoff frequency</td>
</tr>
<tr>
<td>( F^{\text{res}} )</td>
<td>( \Omega )</td>
<td>272 cm(^{-1}) normal mode frequency</td>
</tr>
<tr>
<td>( \mu )</td>
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<td>site mass</td>
</tr>
<tr>
<td>( F^{\text{thermo}} )</td>
<td>( \gamma^{-1} )</td>
<td>0.1 ps phonon-phonon relaxation time</td>
</tr>
<tr>
<td>( T_B )</td>
<td>300 K</td>
<td>bath temperature</td>
</tr>
</tbody>
</table>

to the dynamics of the confinement radii \( \ell \). The coherent vibronic effects are produced by the coupling between the electronic degrees of freedom and \( \ell \), via the Ehrenfest forces, as describes by Eq. (8). The dissipative vibronic effects are described by the Redfield relaxation tensor.

Before performing the quantum dynamics simulations, we thermalize the system to obtain the initial configuration of the \( (\ell_i, p_i) \) for each molecular site \( i \). To do so, we first run the dynamics with only the classical framework of the model, without the excitation of the electron-hole pair. Thus, the kinetic energy of the on-site confinement harmonic oscillator equilibrates with the bath temperature.

Once \( \sigma_{\text{adiabatic}}^{\text{el/hl}} \) is obtained from equation Eq. (14), it is transformed to the diabatic local basis by \( \sigma_{\text{diabatic}}^{\text{el/hl}} = \hat{U}^{\text{el/hl}} \sigma_{\text{adiabatic}}^{\text{el/hl}} (\hat{U}^{\text{el/hl}})^{-1} \), where \( \hat{U}^{\text{el/hl}} \) is the unitary operator that diagonalizes \( H^{\text{el/hl}} \). Although electrons and holes are represented by independent reduced density matrices, namely \( \sigma^{\text{el}} \) and \( \sigma^{\text{hl}} \), the dynamics of one affects the other via the electron-hole binding term of Eq. (5).

B. Energetic Driving Force and Photovoltaic Efficiency

The energy difference \( E_g^{\text{opt}} - E_{CS} = E_{CB}(D) - E_{CB}(A) \) is considered the energetic driving force for charge generation in organic solar cells (OSC).\(^{27,28}\) The energy \( E_{CT} \) is alternatively used for this
FIG. 3. Heterojunction comprised of 84 sites, consisting of a hole drain layer, donor material sites, acceptor material sites, and electron drain layer. The photoexcitation is considered to occur in the middle of the donor region, as depicted by the yellow circle in the figure. The radius of the molecular sites and the lattice parameter are drawn to scale.

definition, but $E_{CT}$ in our model is given by the dynamics simulations, via $E_{\text{bind}}$, rather than being a parameter. Thus, we use the former definition. In this section we vary the energy offset $E_{DA} \equiv E_{CB}(D) - E_{CB}(A)$ to analyse its effect on the charge generation and on the photovoltaic conversion efficiency of an OSC.

We varied $E_{DA}$ from 0 to 0.4 eV, while keeping the offset of the valence band fixed at 0.3 eV; notice that the photoexcitation is assumed to take place in the donor material and that recombination effects are not included in the model. The simulations were carried out with the quantum dissipative and Berendsen baths at $T_B = 300$ K; no electric fields were applied. Figure 4-a) shows the electron population collected by the drain sites ($N_e$) as a function of $E_{DA}$. According to the model simulations, the charge collection is optimal for $100$ meV $\leq E_{DA} \leq 200$ meV. Then, instead of increasing with the energetic driving force, the charge generation rate decreases for $E_{DA} \geq 300$ meV. We ascribe this behavior to the Marcus inverted regime, whereby the electron-hole pair dissociation becomes unfavorable as the Gibbs free energy of the process increases.

Egorova et al. showed that the Redfield method is well suited to describe the Marcus inverted regime. The behavior has been observed for various combinations of donor/acceptor blends in planar heterojunctions. Additional insights on this effect are provided in the sections ahead, by analysing the temperature dependence of the charge generation process. For $E_{DA} < 100$ meV, on the other hand, the electron generation rate is also small, in this case due to the lack of driving
force. By comparing the charge generation in fullerene and non-fullerene based solar cells, Qian et al.\textsuperscript{50} reported that the charge separation in polymer/fullerene blends occurs on a sub-300 fs timescale whereas for polymer/NFA blends it happens in timescales of 10-30 ps for materials that exhibit $E_{DA} < 100$ meV. Next we consider the photovoltaic conversion efficiency associated with the different charge generation regimes

![Figure 4](image.png)

**FIG. 4.** a) Electron collection in the drain layer for various energy offsets $E_{DA} \equiv E_{CB}(D) - E_{CB}(A)$. b) Collected electron energy, here defined as the quantity $N_e \times E_{CS}$, where $E_{CS} = E_{CB}(A) - E_{VB}(D)$.

In Figure 4-b) we estimate the ideal photovoltaic energy, $q\Delta V^{\text{ideal}}$, which we define as $q\Delta V^{\text{ideal}} = N_e \times E_{CS}$, with $E_{CS} = E_{CB}(A) - E_{VB}(D)$. It can be associated with the open-circuit voltage as $V_{OC} = \Delta V^{\text{ideal}} - \Delta V^{\text{losses}}$, where $q\Delta V^{\text{losses}}$ represents the energy losses due to the various radiative and non-radiative recombination mechanisms. For the sake of argument, we also assume that $q\Delta V^{\text{losses}}$ is the same for all the cases considered. Thus, for these simulations, the energetic driving force $E_{DA} = 100$ meV provides the highest photovoltaic conversion as well as high charge generation rates during most of the simulation time. Higher values of $E_{DA}$ render lower photovoltaic efficiencies due to higher energy losses at the interface. On the other hand, the case of $E_{DA} = 0$, or $E_{DA} < 100$ meV for that matter, provides an interesting scenario. For $E_{DA} = 0$ the power conversion is small at short times, but it increases slowly until it reaches the highest collected
energy for \( t > 8 \text{ ps} \). This result shows that a small driving force can yield high power conversions in OSC, however, it also requires reduced recombination rates since the charge generation rate is significantly lower for negligible \( E_{DA} \). Indeed, it has been shown that NFAs used in high PCE solar cells exhibit long exciton lifetimes.\(^{51,50,52}\)

C. Effect of vibronic interactions on the charge separation dynamics

In this section we examine the influence of the vibronic couplings on the charge generation dynamics. According to the electron-hole subsystem hamiltonian, Eq. (4), the vibronic couplings have two origins in our model: the intra-molecular Holstein coupling, governed by Eq. (8), and the inter-molecular Peierls coupling produced by \( V_{ij} \), defined in Eq. (6). Both mechanisms are influenced by the classical thermal bath of temperature \( T_B \) that acts on the vibrational coordinates. The intra-molecular Holstein interaction is also responsible for the coupling of the electron-hole subsystem with the quantum bath, through the Redfield relaxation tensor.

The electronic population \( (N_e) \) collected at the electron drain is shown in Figure 5, for increasing energetic driving forces \( (E_{DA}) \) and various bath temperatures \( (T_B) \). The model simulations show, quite generally, that the charge generation rate increases with temperature but, furthermore, the effect of \( T_B \) on \( N_e \) reveals three distinct electron transfer regimes, as depicted in the inset of Figure 5: a) the direct electron transfer for negligible \( E_{DA} = 0 \text{ eV} \); b) the activationless regime for \( E_{DA} \approx 0.1 \text{ eV} \); and c) the inverted Marcus regime for \( E_{DA} = 0.3 \text{ eV} \). In general, little difference is observed for \( T_B = 300 \text{ K to 400 K} \), indicating that the charge generation rate saturates around room temperature. In the activationless regime, for \( E_{DA} \approx 0.1 \text{ eV} \), the process is almost independent of the temperature. The biggest difference is observed for \( T_B = 100 \text{ K (\approx 8.6 meV)} \), though, that shows significantly smaller rates for charge separation.

The underlying processes responsible for the free charge generation in high-efficiency OSC are still a source of debate.\(^{27}\) Perdigón-Toro et at. identified a small activation barrier \((< 10 \text{ meV})\) for the charge generation in high performance PM6:Y6 non-fullerene blends.\(^{53}\) Elsewhere, Gao et al. reported\(^{54}\) activation energies of 9 meV for ordered P3HT:PC\text{60}BM and of 25 meV for less ordered polymer:polymer interfaces. On the other hand, Hinrichsen et al. suggest that, in NFA based solar cells with negligible driving forces, charge-transfer excitons must overcome activation energy barriers of \( \approx 200 \text{ meV} \) to generate free charges over a time period of hundreds of picoseconds at room temperature.\(^{55}\) Our simulations indicate that different tunings of the electron-
FIG. 5. Electronic population \( (N_e) \) collected at the electron drain for various bath temperatures \( (T_B) \) and donor-acceptor energy offsets \( (E_{DA}) \). The illustration is a reference to the Marcus Theory, depicting electron transfer in the direct regime, the activationless regime, and the inverted regime as the \( E_{DA} \) offset increases.

Transfer regime can lead to very different charge separation times, especially at low temperatures.

Although vibrational couplings tend to increase the charge generation yield, the different vibronic mechanisms play different roles. Panel 6 shows the electronic, \( N_e \) (red), and hole, \( N_h \) (blue), densities collected at the respective drain layers. The hole densities are consistently higher because we assume that the photoexcited pair is created in the donor material, closer to the hole drain (see Figure 3). Then, we consider three different scenarios for the vibronic coupling effects: charge generation dynamics considering both the Holstein and Peierls mechanisms (solid-line curves); charge generation with \textit{inter}-molecular Peierls coupling but disregarding the \textit{intra}-molecular Holstein mechanism (dashed-line curves); charge generation without vibrational effects, that is, assuming rigid molecular sites with \( \ell_i = \ell_0 \) (dot-dashed curves). We also consider this situation for different bath temperatures \( T_B \) and donor-acceptor offset of \( E_{DA} = 300 \) meV.

Now, we examine the different features revealed in the panels of Figure 6. First, the lack of vibronic effects (dot-dashed curves) leads to less charge generation. This behavior is in accordance
FIG. 6. Charge collected in the drain layers: $N_e$ (red) and $N_h$ (blue). **Solid lines** describe charge dynamics considering both Holstein and Peierls mechanisms. **Dashed lines** describe charge collection with intermolecular Peierls coupling, but without *intra*-molecular Holstein relaxation. **Dot-dashed lines** describe charge collection without vibrational effects. The bath temperatures are: a) 100 K, b) 200 K, c) 300 K and d) 400 K. Donor-acceptor offset is $E_{DA} = 300$ meV.

with the trend exhibited in Figure 5, namely, the charge generation increases with the bath temperature, favoring endothermic processes. It corroborates studies\(^{51,56,57}\) that show that the mixing of electronic and vibronic degrees of freedom improves the charge transport\(^{23}\) and, more importantly, the vibrational effects help the electron-hole pair overcome the binding energy to give rise to the charge separated state\(^{27,55}\). Interestingly, though, when we shut off the Holstein relaxation mechanism (dashed curve) the charge generation improves further in comparison with the full vibronic scenario (solid curve), particularly for the lower bath temperatures. We ascribe this effect to the polaron formation, that relaxes the carriers to a lower electronic energy state, rendering them less mobile. As the bath temperature $T_B$ increases, the carriers are forced to move due to the background energy of the bath and the Peierls mechanism. Thus, for higher bath temperatures the
Peierls mechanism overwhelms the polaronic effects, whereas for low $T_B$ the Holstein relaxation effect significantly hampers the charge generation. The enhancement of charge transfer due to the Peierls coupling mechanism, evinced in our simulations, is also reported in other studies.\textsuperscript{40,58} We recall that the effect is more pronounced for the electron, since it is created farther from the drain, on the opposite side of the interface.

We must take into consideration, however, that the mixed quantum-classical approach based on the Ehrenfest method tends to overestimate the occupation of electronic excited-states in comparison with the surface hopping method, for instance.\textsuperscript{59} Therefore, we have to keep in mind that the results shown in Figure 6 may overestimate the vibronic effects for the higher temperatures of the bath.

IV. ELECTRON-HOLE BINDING

In this final section we analyse the electron-hole binding energy through the dynamics simulations, as evinced in Figure 7 for different energetic driving forces ($E_{DA}$) and various bath temperatures ($T_B$). To do so, we examine the quantity $E_{\text{bind}} = \text{Tr}[\sigma^{\text{el}}\Phi^{\text{el}} + \sigma^{\text{hl}}\Phi^{\text{hl}}]$, with $\Phi^{\text{el/HL}}$ given by Eq. (5). For the parameters given in Table I, $E_{\text{bind}}(t = 0) = 400$ meV for all the cases considered, with the electron and hole occupying the same molecular site. For $t = 10$ fs, $E_{\text{bind}}$ decreases to $\sim 200$ meV, that corresponds to approximately 10% of the electron and hole populations transferred to each of the 4 nearest neighbor molecular sites. As the dynamics proceeds, $E_{\text{bind}}$ decays by another half to approximately 100 fs, so that $E_{\text{bind}}(100$ fs$) \approx 100$ meV. The initial decay of $E_{\text{bind}}$ that occurs for $t \lesssim 100$ fs is temperature independent and practically identical for all energy offsets. Thus, we ascribe this initial decay to the excitonic spread in the donor material. Then, the decay of $E_{\text{bind}}$ becomes significantly slower and temperature dependent, indicating the onset of the CT state dissociation. In our simulations $E_{\text{bind}}$ saturates at approximately 25 meV, however, this is actually an artifact due to the finite size of the model. This value corresponds to the energy of the electron and hole populations trapped apart in their respective drain layers (see Figure 3).

In Figure 7 we also estimate the time the electron-hole pair would take to separate into free charges, by extrapolating the curves until $E_{\text{bind}} = 10$ meV. For $E_{DA} = 0.3$ eV, it takes $\sim 30$ ps for the binding energy between electron and hole to decrease to values much smaller than the available thermal energy at $T_B = 300$ K. However, for the same energy offset and $T_B = 100$ K, the time required for complete dissociation should exceed 100 ps. For the activationless regime,
FIG. 7. a) Electron-hole binding energy as function of time, as given by $E_{\text{bind}} = \text{Tr}[\sigma^{\text{el}} \Phi^{\text{el}} + \sigma^{\text{hl}} \Phi^{\text{hl}}]$, for $E_{DA} = 0.3$ meV (a), 0.1 eV (b) and 0 eV (c), and bath temperatures $T_B = 100$, $200$, $300$ and $400$ K. The extrapolation of the curves is used to estimate the electron-hole separation time.

Figure 7-b), the charge separation is practically temperature independent for $T_B > 200$ K. Notice that the driving force and the temperature seem to assist the charge separation in Figure 7-a),
though. Finally, for negligible driving forces, Figure 7-c), the final charge separation occurs much later, in addition to being strongly temperature dependent. In particular, for \( T_B < 200 \text{ K} \) the charge separation should take several hundreds of picoseconds to occur, if at all.

It is important to notice that the specific behavior of the simulation is dependent on the model parameters, and the results reflect the parameters given in Table I. Even so, the simulations show that initially \( E_{\text{bind}} \) looses most of its strength on a sub-100 fs timescale, so that when the dissociation of the CT state initiates \( E_{\text{bind}} \) is actually much smaller than the exciton binding energy of the isolated molecular species.

Generally, in order to simplify the description, the charge generation process is described as a succession of independent and sequential steps, such as: exciton diffusion to the interface, stabilization of the CT state, dissociation of the CT into CS state. However, the simulation results show that charge generation is facilitated if these mechanisms operate concomitantly.

V. CONCLUSIONS

We studied the influence of the energetic driving force and the vibronic effects on the charge generation and photovoltaic energy conversion of OSCs. The charge generation process is modelled by a coarse grained mixed quantum-classical model that provides relevant insights into the charge generation process in small energy offset interfaces. The simulations show that maximum charge generation occurs for a driving force \( E_{DA} = E_{\text{opt}} - E_{CS} \approx 100 \text{ to } 200 \text{ meV} \), corresponding to the activationless electron transfer regime. The photovoltaic energy conversion, on the other hand, is more sensitive to the energetic driving force and shows maximum efficiency for \( E_{DA} \lesssim 100 \text{ meV} \). By analyzing the effects of the Holstein and Peierls vibrational couplings, we also examined the influence of vibronic couplings on the charge generation. We find, quite generally, that vibrational couplings produce an overall effect of improving the charge generation. However, the two vibronic mechanisms play different roles. The Holstein relaxation mechanism decreases the charge generation due to the formation of the polaron, particularly for \( T_B < 200 \text{ K} \). The Peierls mechanism always assists the charge generation and, for \( T_B > 200 \text{ K} \), it tends to overwhelm the Holstein mechanism effects. Since the model does not take into account the recombination losses, the influence of this mechanism is considered only qualitatively. Finally, by examining the time-dependent electron-hole binding energy, we evince two distinct regimes for charge dissociation: the temperature independent excitonic spread on the sub-100 fs timescale and the CT state dis-
sociation on the timescale of tens of picoseconds, so that when the electron-hole pair reaches the interface its binding energy is much smaller that the initial excitonic binding energy.

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Appendix A: Ehrenfest Force

Writing the time dependent wave function for the electron and hole in terms of the diabatic basis of the system, we have

\[ |\Psi_{\text{el/hl}}(t)\rangle = \sum_i C_{\text{el/hl}}^i(t) |i\rangle \]  

(A1)

where the elements of reduced density matrix are defined \( \sigma_{ij}^{\text{el/hl}} = C_{\text{el/hl}}^i(t) C_{\text{el/hl}}^* j(t) \). In the next equations, the superscripts for electron and hole will be omitted for the sake of clarity. The RHS of Eq. (9) turns

\[ \frac{\partial U}{\partial \ell_k} = \sum_{i,j} \left\{ H_{ij} \left( \frac{\partial C_j^*(t)}{\partial \ell_k} C_j(t) + C_j^*(t) \frac{\partial C_j(t)}{\partial \ell_k} \right) + C_j^*(t) \frac{\partial H_{ij}}{\partial \ell_k} C_j(t) \right\} \]  

(A2)

Using the time dependent Schrödinger equation, we have

\[ \frac{dC_j(t)}{dt} = -\frac{i}{\hbar \ell_k} \sum_n C_n(t) H_{jn} - \sum_n C_n(t) \langle j | \frac{\partial n}{\partial \ell_k} \rangle \]  

(A3)

Thus

\[ \sum_{i,j} \left\{ H_{ij} \left( \frac{\partial C_i^*(t)}{\partial \ell_k} C_j(t) + C_i^*(t) \frac{\partial C_j(t)}{\partial \ell_k} \right) = \frac{i}{\hbar \ell_k} \sum_{i,j,n} H_{ij} (H_{in} \sigma_{jn} - H_{jn} \sigma_{ni}) - \right. \]

\[ \left. - \sum_{i,j,n} H_{ij} \left( \sigma_{jn} \langle i | \frac{\partial n}{\partial \ell_k} \rangle + \sigma_{ni} \langle j | \frac{\partial n}{\partial \ell_k} \rangle \right) \]  

(A4)
The term $\sum_{i,j,n} H_{ij}(H_{jn}\sigma_{jn} - H_{jn}\sigma_{ni})$ is zero, what can be proven using the cyclic property of trace. We also suppress the second term in RHS of equation (A4), since we are considering the non-orthogonality only with the form factor $F(\ell_i, \ell_j, d_{ij})$ term. Thus
\[
\frac{\partial U}{\partial \ell_k} = \sum_{i,j} C_i^*(t) \frac{\partial H_{ij}}{\partial \ell_k} C_j(t) = \sum_{i=j} \sigma_{ii} \frac{\partial e_i}{\partial \ell_k} + \sum_{i\neq j} \sigma_{ij} \frac{\partial V_{ij}}{\partial \ell_k}.
\] (A5)

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